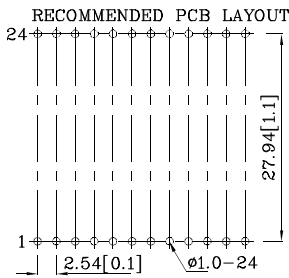
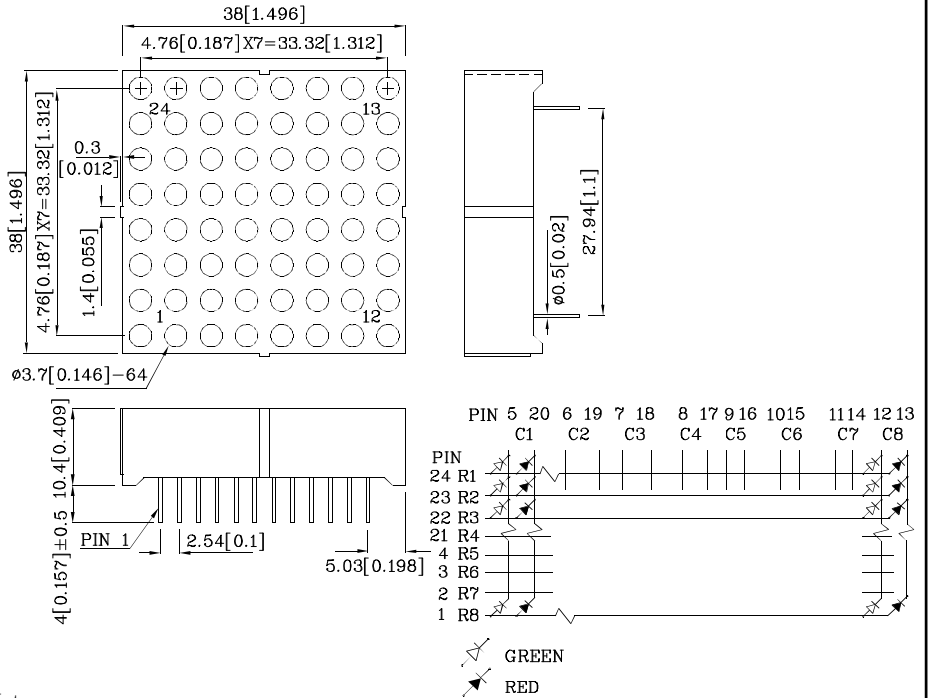


**Features**

- Low power consumption
- Robust package
- I.C. Compatible
- Standard configuration: Gray face w/ white dots
- Optional black face provides superior color contrast
- RoHS Compliant



**Package Schematics**



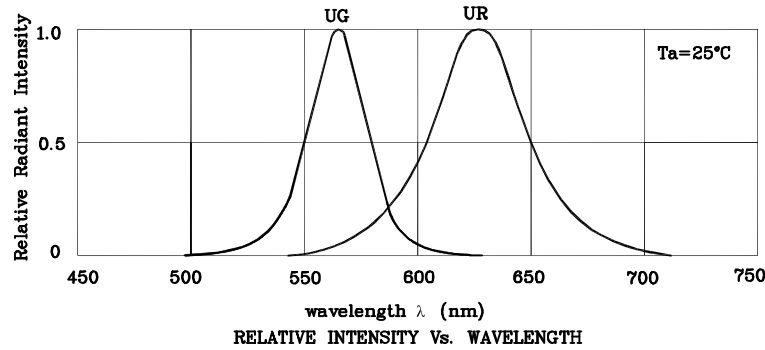
**Notes:**

1. All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01") unless otherwise noted.
2. Specifications are subject to change without notice.

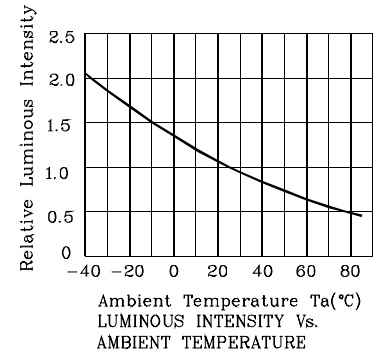
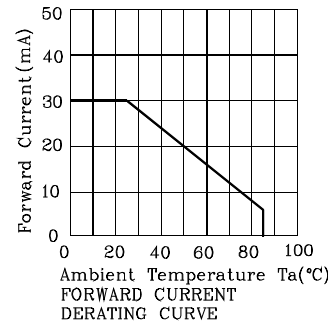
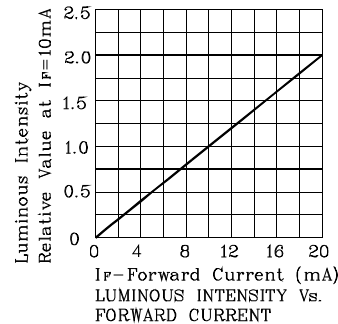
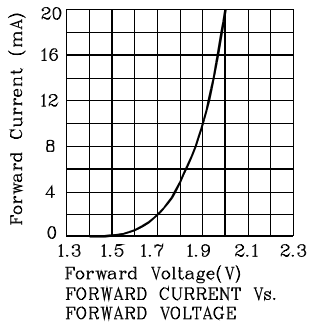
Absolute Maximum Ratings (T <sub>A</sub> =25°C)		UR (GaAsP/ GaP)	UG (GaP)	Unit
Reverse Voltage	V <sub>R</sub>	5	5	V
Forward Current	I <sub>F</sub>	30	25	mA
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	i <sub>FS</sub>	160	140	mA
Power Dissipation	P <sub>D</sub>	75	62.5	mW
Operating Temperature	T <sub>A</sub>	-40 ~ +85		°C
Storage Temperature	T <sub>stg</sub>	-40 ~ +85		
Lead Solder Temperature [2mm Below Package Base]	260°C For 3~5 Seconds			

Operating Characteristics (T <sub>A</sub> =25°C)		UR (GaAsP/GaP)	UG (GaP)	Unit
Forward Voltage (Typ.) (I <sub>F</sub> =10mA)	V <sub>F</sub>	1.9	2	V
Forward Voltage (Max.) (I <sub>F</sub> =10mA)	V <sub>F</sub>	2.5	2.5	V
Reverse Current (Max.) (V <sub>R</sub> =5V)	I <sub>R</sub>	10	10	uA
Wavelength of Peak Emission (Typ.) (I <sub>F</sub> =10mA)	λ <sub>P</sub>	627	565	nm
Wavelength of Dominant Emission (Typ.) (I <sub>F</sub> =10mA)	λ <sub>D</sub>	625	568	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =10mA)	Δλ	45	30	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	C	15	15	pF

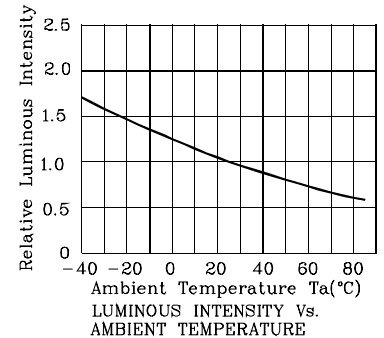
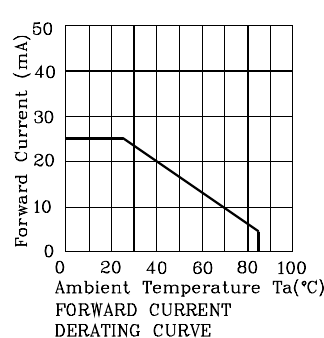
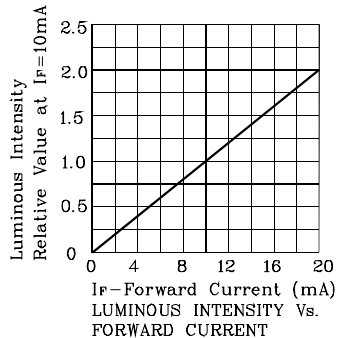
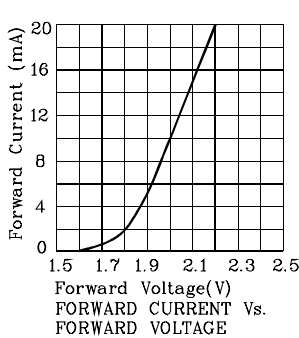
Part Number	Emitting Color	Emitting Material	Luminous Intensity (I <sub>F</sub> =10mA) ucd		Wavelength nm λ <sub>P</sub>	Description
			min.	typ.		
XMURG38C8	Red	GaAsP/GaP	5600	12990	627	Column Cathode
	Green	GaP	9000	19990	565	



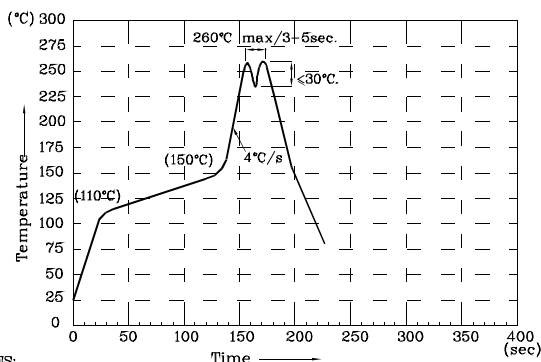
❖ UR



❖ UG



Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



- NOTES:
1. Recommend the wave temperature 245°C~260°C. The maximum soldering temperature should be less than 260°C.
  2. Do not apply stress on epoxy resins when temperature is over 85°C.
  3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
  4. During wave soldering, the PCB top-surface temperature should be kept below 105°C.
  5. No more than once.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

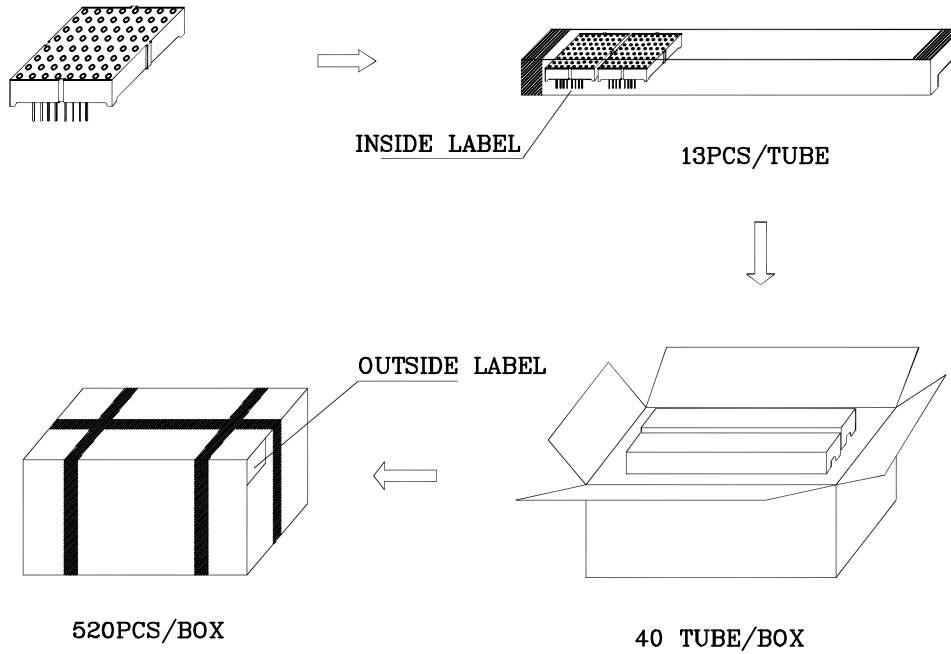
the typical accuracy of the sorting process is as follows:

1. Wavelength: +/-1nm
2. Luminous Intensity / Luminous Flux: +/-15%
3. Forward Voltage: +/-0.1V

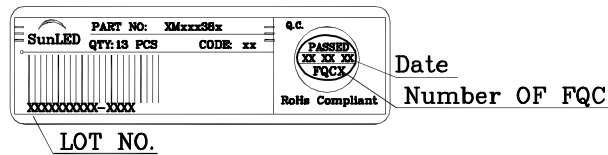
Note: Accuracy may depend on the sorting parameters.



PACKING & LABEL SPECIFICATIONS



Inside Label On IC-tube



Outside Label On Box

